# NSN 5961-00-139-2204

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Inclosure Material:

Metal

**Overall Length:** 

0.300 inches

## **Overall Diameter:**

0.830 inches

# Mounting Facility Quantity:

2

## Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

Features Provided:

#### Hermetically sealed case

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

90.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown

voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

Between 1.00 amperes source cutoff current and 5.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

87.5 watts small-signal input power, common-collector absolute

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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